

In re Patent Application of  
RAYNOR  
Serial No. Not Yet Assigned  
Filed: Herewith

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In the Claims:

Claims 1-13 (Cancelled).

14. (New) A solid state image sensor comprising:  
a substrate of a first conductivity type;  
an epitaxial layer of the first conductivity type on  
said substrate; and

an active pixel array in said epitaxial layer, each  
pixel comprising

a first well of a second conductivity type  
functioning as a collection node, and

at least one second well of the first  
conductivity type adjacent said first well, and  
comprising a plurality of MOS transistors of only  
the second conductivity type functioning as active  
elements of said pixel.

15. (New) A solid state image sensor according to  
Claim 14, wherein the first conductivity type comprises a P-  
type conductivity, and the second conductivity type comprises  
an N-type conductivity.

16. (New) A solid state image sensor according to  
Claim 14, wherein the first conductivity type comprises an N-  
type conductivity, and the second conductivity type comprises  
a P-type conductivity.

17. (New) A solid state image sensor according to  
Claim 14, further comprising circuit elements external said  
active pixel array; and wherein said active elements in each  
pixel and said external circuit elements form part of an

In re Patent Application of  
**RAYNOR**  
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analog-to-digital converter.

18. (New) A solid state image sensor according to Claim 17, further comprising at least one comparator external said active pixel array; and wherein said active elements in each pixel form an amplifier connected to said at least one comparator for forming part of the analog-to-digital converter.

19. (New) A solid state image sensor according to Claim 18, wherein said active elements in each pixel are selectively switched to said at least one comparator.

20. (New) A solid state image sensor according to Claim 18, wherein said circuit elements external each pixel comprise at least one current mirror connected to said at least one comparator; and wherein said active elements in each pixel form a differential amplifier for receiving a pixel photodiode voltage and a reference voltage, and for providing a balanced output to said at least one current mirror connected thereto.

21. (New) A solid state image sensor according to Claim 18, further comprising a latch connected to said at least one comparator in which a count is latched by a change of state of said at least one comparator.

22. (New) A solid state image sensor according to Claim 21, further comprising a frame store circuit connected to said latch for receiving the count latched by said latch.

In re Patent Application of  
**RAYNOR**  
Serial No. Not Yet Assigned  
Filed: Herewith

---

23. (New) A solid state image sensor according to Claim 20, wherein the reference voltage is ramped during a time when each pixel is integrating a photo induced current.

24. (New) A solid state image sensor according to Claim 20, wherein the reference voltage is ramped during reset of each pixel to provide an offset compensation.

25. (New) A solid state image sensor according to Claim 14, further comprising circuit elements external said active pixel array, said external circuit elements comprising a respective comparator and counter for each pixel.

26. (New) A solid state image sensor according to Claim 14, further comprising circuit elements external said active pixel array, said external circuit elements comprising comparators and counters, and wherein a number of pixels in a given row or column of said active pixel array share a single comparator and counter, with the corresponding pixels in the given row or column being enabled sequentially.

27. (New) A solid state image sensor according to Claim 26, wherein said active elements in each pixel form a differential amplifier, and outputs of said differential amplifier are multiplexed to a pair of output lines common to the corresponding pixels in the given row or column.

28. (New) A solid state image sensor according to Claim 27, wherein the active elements in each pixel further comprise cascode transistors connected to the outputs of each differential amplifier.

In re Patent Application of  
**RAYNOR**  
Serial No. Not Yet Assigned  
Filed: Herewith

---

29. (New) A solid state image sensor comprising:  
a substrate;  
an active pixel array in said substrate, each pixel  
comprising

a first well of a first conductivity type  
functioning as a collection node, and

at least one second well of a second  
conductivity type adjacent said first well, and  
comprising a plurality of MOS transistors of only  
the first conductivity type functioning as active  
elements; and

circuit elements in said substrate and external said  
active pixel array and forming analog-to-digital converters  
with the active elements therein.

30. (New) A solid state image sensor according to  
Claim 29, wherein said substrate is of the second conductivity  
type; and wherein the first conductivity type comprises a P-  
type conductivity and the second conductivity type comprises  
an N-type conductivity.

31. (New) A solid state image sensor according to  
Claim 29, wherein said substrate is of the first conductivity  
type; and wherein the first conductivity type comprises an N-  
type conductivity and the second conductivity type comprises a  
P-type conductivity.

32. (New) A solid state image sensor according to  
Claim 29, wherein said circuit elements external each pixel  
comprise at least one comparator; and wherein said active

In re Patent Application of  
**RAYNOR**  
Serial No. **Not Yet Assigned**  
Filed: **Herewith**

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elements in each pixel form an amplifier connected to said at least one comparator for forming an analog-to-digital converter.

33. (New) A solid state image sensor according to Claim 32, wherein said active elements in each pixel are selectively switched to said at least one comparator.

34. (New) A solid state image sensor according to Claim 32, wherein said circuit elements external each pixel comprise at least one current mirror connected to said at least one comparator; and wherein said active elements in each pixel form a differential amplifier for receiving a pixel photodiode voltage and a reference voltage, and for providing a balanced output to said at least one current mirror connected thereto.

35. (New) A solid state image sensor according to Claim 32, further comprising a latch connected to said at least one comparator in which a count is latched by a change of state of said at least one comparator.

36. (New) A solid state image sensor according to Claim 35, further comprising a frame store circuit connected to said latch for receiving the count latched by said latch.

37. (New) A solid state image sensor according to Claim 34, wherein the reference voltage is ramped during a time when each pixel is integrating a photo induced current.

38. (New) A solid state image sensor according to

In re Patent Application of  
**RAYNOR**  
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Claim 34, wherein the reference voltage is ramped during reset of each pixel to provide an offset compensation.

39. (New) A solid state image sensor according to Claim 29, wherein said circuit elements external each pixel further comprise a respective comparator and counter for each pixel.

40. (New) A solid state image sensor according to Claim 29, wherein said circuit elements external each pixel further comprise comparators and counters for said active pixel array, and wherein a number of pixels in a given row or column of said active pixel array share a single comparator and counter, with the pixels being enabled sequentially.

41. (New) A solid state image sensor according to Claim 40, wherein said active elements in each pixel form a differential amplifier, and outputs of said differential amplifier are multiplexed to a pair of output lines common to the corresponding pixels in the given row or column.

42. (New) A solid state image sensor according to Claim 41, wherein the active elements in each pixel further comprise cascode transistors connected to the outputs of each differential amplifier.

43. (New) A method for making a solid state image sensor comprising:

forming an active pixel array in a substrate, and  
forming each pixel comprising

forming a first well of a first conductivity

In re Patent Application of  
RAYNOR  
Serial No. Not Yet Assigned  
Filed: Herewith

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type functioning as a collection node, and  
forming at least one second well of a second  
conductivity type adjacent the first well, the at  
least one second well comprising a plurality of MOS  
transistors of only the first conductivity type  
functioning as active elements; and  
forming circuit elements in the substrate external  
the active pixel array and forming analog-to-digital  
converters with the active elements therein.

44. (New) A method according to Claim 43, wherein  
the circuit elements external each pixel comprise at least one  
comparator; and wherein the active elements in each pixel form  
an amplifier connected to the at least one comparator for  
forming an analog-to-digital converter.

45. (New) A method according to Claim 44, wherein  
the active elements in each pixel are selectively switched to  
the at least one comparator.

46. (New) A method according to Claim 44, wherein  
the circuit elements external each pixel comprise at least one  
current mirror connected to the at least one comparator; and  
wherein the active elements in each pixel form a differential  
amplifier for receiving a pixel photodiode voltage and a  
reference voltage, and for providing a balanced output to the  
at least one current mirror connected thereto.

47. (New) A method according to Claim 44, further  
comprising a latch connected to the at least one comparator in  
which a count is latched by a change of state of the at least

In re Patent Application of  
**RAYNOR**  
Serial No. Not Yet Assigned  
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one comparator.

48. (New) A method according to Claim 47, further comprising a frame store circuit connected to the latch for receiving the count latched by the latch.

49. (New) A method according to Claim 43, wherein the circuit elements external each pixel further comprise a respective comparator and counter for each pixel.

50. (New) A method according to Claim 43, wherein the circuit elements external each pixel further comprise comparators and counters for the active pixel array, and wherein a number of pixels in a given row or column of the active pixel array share a single comparator and counter, with the pixels being enabled sequentially.

51. (New) A method according to Claim 50, wherein the active elements in each pixel form a differential amplifier, and outputs of the differential amplifier are multiplexed to a pair of output lines common to the corresponding pixels in the given row or column.